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VOLUME 1

- ◆ *Plenary Session*
- ◆ *Nanoelectronics*
- ◆ *RF MEMS*
- ◆ *Microphotonics*
- ◆ *Microsystems Technology*
- ◆ *Advanced Microwave Devices and Circuits*
- ◆ *RF MEMS, Microwave Devices and Circuits*

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CONTENTS

PLENARY SESSION 1

INVITED PAPER	<i>HOW MANY GATES DO WE NEED IN A TRANSISTOR ?</i> , S. Cristoloveanu, CNRS-INPG-UJF, Grenoble, France.....	3
INVITED PAPER	<i>FROM GATE-ALL-AROUND TO NANOWIRE MOSFETS</i> , J.-P. Colinge, Tyndall National Inst., Cork, Ireland.....	11

PLENARY SESSION 2

INVITED PAPER	<i>TCADMEMS OVERVIEW</i> , D. Peyrou, I. Achkar, F. Pennec, F. Coccetti, M. Al Ahmad, P. Pons, R. Plana, LAAS-CNRS, Univ. of Toulouse, France.....	21
INVITED PAPER	<i>HIGH FREQUENCY CARBON NANOSTRUCTURES THAT SMELL, WEIGHT, HARVEST AND HANDLE</i> , M. Dragoman, IMT-Bucharest, Romania.....	25

Session N: NANOELECTRONICS Oral presentations

INVITED PAPER	<i>QUASI BALLISTIC TRANSPORT IN ADVANCED MOSFET DEVICES</i> , R. Clerc, P. Palestri*, Q. Rafhay, M. Ferrier*, G. Pananakakis, G. Ghibaudo, L. Selmi*, IMEP, Minatec, Grenoble, France, *DIEGM, Univ. Udine, Italy.....	35
N.1	<i>WHY THE ENERGY LEVELS OBSERVED IN ELECTRICAL TRANSPORT, PHOTOTRANSPORT AND PHOTOLUMINESCENCE ARE DIFFERENT ?</i> , M.L. Ciurea, V. Iancu*, INCD-FM, **Politehnica” Univ. of Bucharest, Romania.....	41
N.2	<i>SINGLE DEVICE LOGIC USING 3D GATING OF SCREEN GRID FIELD EFFECT TRANSISTORS</i> , Y. Shadrokh, K. Fobelets, J.W. Velazquez-Perez*, Imperial College London, UK, *Univ. of Salamanca, Spain.....	45
N.3	<i>MANUFACTURABILITY ISSUES OF REDUNDANT NANOGATES</i> , F. Martorell, S.D. Cotofana*, A. Rubio, Polytechnical Univ. of Catalonia, Spain, *TU Delft, The Netherlands.....	49
N.4	<i>HIGH FREQUENCY DEVICES BASED ON GRAPHENE</i> , M. Dragoman ¹ , D. Dragoman ² , A.A. Muller ³ , ¹ IMT-Bucharest, ² Univ. Bucharest, Romania, ³ Technische Univ. Munchen, Germany.....	53

Session MT1: MICROSYSTEM TECHNOLOGY 1 Oral presentations

INVITED PAPER	<i>SENSING AND TRANSDUCTION IN SEMICONDUCTING MOX GAS SENSORS; PHENOMENOLOGICAL AND SPECTROSCOPIC INVESTIGATIONS</i> , N. Barsan, D. Koziej, U. Weimar, Inst. of Physical and Theoretical Chemistry, Tübingen, Germany.....	59
INVITED PAPER	<i>MANIPULATION OF BIOLOGICAL SAMPLES USING ELECTRIC FIELD</i> , C. Iliescu ¹ , G.L. Xu ¹ , P.L. Ong ¹ , L. Yu ² , F.E.H. Tay ^{1,2} , F.S. Iliescu ³ , G. Tresset ¹ , ¹ Inst. of Bioengineering and Nanotechnology, Singapore, ² National Univ. of Singapore, ³ Republic Polytechnic, Singapore.....	67

MT1.1	<i>MODELLING AND SIMULATION OF A PNEUMATICALLY ACTUATED MICROPUMP</i> , O.T. Nedelcu¹, J.-L. Morelle², C. Tibeica¹, S. Voccia², I. Codreanu¹, S. Dahms³ , ¹ IMT-Bucharest, Romania, ² Trasis SA, Liege, Belgium, ³ Bartels GmbH, Dortmund, Germany...	77
MT1.2	<i>EXPERIMENTAL STUDY CONCERNING THE INFLUENCE OF THE BASE FLUID PROPERTIES ON THE THERMAL CONDUCTIVITY OF NANOFLUIDS</i> , C. Codreanu, R. Gavrilă, I. Morjan* , IMT-Bucharest, *INFLPR, Bucharest, Romania.....	81

Session MT2: MICROSYSTEM TECHNOLOGY 2

Poster presentations

MT2.1	<i>DIFFERENTIAL PIEZORESISTIVE PRESSURE SENSOR</i> , B. Firtat, C. Moldovan, R. Iosub, D. Necula, M. Nisulescu , IMT-Bucharest, Romania.....	87
MT2.2	<i>PLASMA SURFACE MODIFICATION OF POLYMER SUBSTRATES FOR SELECTIVE HYDROPHOBIC CONTROL</i> , M. Avram, M.A. Avram, A. Bragaru, A. Ghiu, C. Iliescu* , IMT-Bucharest, Romania, *Inst. of Bioengineering and Nanotechnology, Singapore.....	91
MT2.3	<i>SIMULATION OF MOISTURE DIFFUSION IN SEALING LAYERS BY USING ANALOGOUS THERMAL SIMULATION</i> , C. Tibeica, R. Voicu, V. Moagar-Poladian , IMT-Bucharest, Romania.....	95
MT2.4	<i>INVESTIGATION OF THE PIEZOELECTRIC PROPERTIES OF THE THIN FILMS BY AFM</i> , F. Craciunoiu, M. Miu, R. Gavrilă, A. Dinescu, E. Hamciuc* , IMT-Bucharest, *Inst. of Macromolecular Chemistry, Iasi, Romania.....	99
MT2.5	<i>RELIABILITY ACCELERATED TESTING OF MEMS ACCCELEROMETERS</i> , M. Bazu, L. Galateanu, V.E. Ilian, J. Loicq*, S. Habraken*, J.P. Colette* , IMT-Bucharest, Romania, *Univ. de Liege, Belgium.....	103
MT2.6	<i>TECHNOLOGICAL METHODS FOR LOW TEMPERATURE MICROFLUIDIC DEVICES MICROFABRICATION</i> , A. Coraci, C. Podaru, E. Manea, E. Iancu, A. Ciuciumis, A. Popescu, O. Corici* , IMT-Bucharest, *Oilfield Schlumberger, Bucharest, Romania.....	107
MT2.7	<i>ROBUST ASSEMBLING SYSTEM FOR PHOTOSYNTHESIS-BASED MICROBIOSENSORS</i> , L. Galateanu, N. Cimpoca, M. Bazu, V. Ilian, A. Dinescu , IMT-Bucharest, Romania.....	111
MT2.8	<i>CHARACTERISATION OF SOL-GEL HYBRID THIN FILMS FOR SWITCHING DEVICES</i> , A. Dima¹, I. Rendina², F. Della Corte², M. Dima³ , ¹ Univ. of Liverpool, UK, ² Inst. per la Microelettronica e Microsistemi, Napoli, Italy, ³ Inst. for Nuclear Physics, Bucharest, Romania..	115
MT2.9	<i>A GRAY-TONS DERIVED LITHOGRAPHY METHOD FOR SILICON MICROMACHINING</i> , F. Craciunoiu , IMT-Bucharest, Romania.....	119
MT2.10	<i>PROFILED METAL – CERAMIC MATRICES FOR MEMS APPLICATION</i> , C. Anton¹, J.P. Lecompte², M. Muntean³ , ¹ IMT-Bucharest, Romania, ¹ Univ. de Limoges, ENSIL, France, ³ "Politehnica" Univ. of Bucharest, Romania.....	123
MT2.11	<i>SOLAR PANEL ENERGETIC EFFICIENCY OPTIMIZATION METHOD, BASED ON AN SPECIFIC DETECTOR AND ORIENTATION MICROSYSTEM</i> , O. Oltu, P.L. Milea, M. Dragulinescu, E. Franti* , "Politehnica" Univ. of Bucharest, *IMT-Bucharest, Romania....	127
MT2.12	<i>BIOMEMS MICROPROBE FOR ELECTRICAL ACTIVITY RECORDING OF LIVING CELLS</i> , C. Moldovan¹, R. Iosub¹, C.P. Lungu², A.M. Lungu², B. Firtat¹, C. Roman¹, R. Albuлесcu³ , IMT-Bucharest, *INFLPR, Bucharest, Nat. Inst. for Chemical-Pharmaceutical R&D, Bucharest, Romania.....	131

MT2.13	<i>SURFACE FUNCTIONALIZATION FOR PROTEIN MICROARRAY</i> , M. Simion, L. Ruta*, I. Kleps, C. Mihailescu*, T. Ignat, D. Stan*, F. Craciunoiu, M. Miu, A. Bragaru, IMT-Bucharest, *DDS Diagnostic, Bucharest, Romania.....	135
MT2.14	<i>LOW STRESS PECVD SiNx PROCESS FOR BIOMEDICAL APPLICATION</i> , C. Ilescu, J. Wei, P.L. Ong, B. Chen, Inst. of Bioengineering and Nanotechnology, Singapore.....	139
MT2.15 #	<i>SIMULATION AND DESIGN OF A MICROCANTILEVER FOR BIOSENSING APPLICATION</i> , M. Ion, C. Pachiu, C. Moldovan, IMT-Bucharest, Romania.....	143
MT2.16	<i>APTS BIO-FUNCTIONALIZATION OF POROUS SILICON NANOSTRUCTURED SURFACE</i> , A. Bragaru, M. Simion, M. Miu, T. Ignat, I. Kleps, V. Schiopu, M.A. Avram, F. Craciunoiu, IMT-Bucharest, Romania.....	147
MT2.17	<i>INVESTIGATION OF LIPOSOME BASED CHONDROITIN SULPHATE EFFECTS ON HUMAN CHONDROCYTES</i> , M. Trif ¹ , L. Moldovan ² , O. Zarnescu ³ , ¹ Inst. of Biochemistry, ² National Inst. R&D for Biological Sciences, ³ Univ. of Bucharest, Bucharest, Romania.....	151
MT2.18	<i>ADVANCED LASER MICROPROCESSING FOR SUBSTRATES MICROPROCESSING OF MICROSYSTEMS AND OPTOELECTRONICS DEVICES APPLICATIONS</i> , D. Ilieru ¹ , A. Tantau ² , E. Ulieru ² , Cernica ³ , A. Matei ³ , V. Schiopu ³ , F. Pistritu ³ , ¹ ROMES SA, ² SITEX 45 SRL, ³ IMT-Bucharest, Romania.....	155
MT2.19	<i>DESIGN AND FINITE ELEMENT SIMULATION OF MEMS FOR FATIGUE TEST</i> , G. De Pasquale, A. Soma, Politecnico di Torino, Italy.....	159

Session O1: MICROPHOTONICS 1

Oral presentations

INVITED PAPER	<i>HIGH-PERFORMANCE 1.3 μm DILUTE-NITRIDE EDGE-EMITTING LASERS</i> , M. Dumitrescu ¹ , A. Larsson ² , Y. Wei ² , E. Larkins ³ , P. Uusimaa ⁴ , K. Schulz ⁵ , M. Pessa ¹ , ¹ Tampere Univ. of Technology, Finland, ² Chalmers Univ. of Technology, Sweden, ³ Univ. of Nottingham, UK, ⁴ Modulight Inc., Finland, ⁵ MergeOptics GmbH, Germany.....	165
INVITED PAPER	<i>SILICON PHOTONICS AT UNIVERSITY OF TRENTO</i> , E.O. Anopchenko, P. Bettotti, M. Cazzanelli, N. Daldosso, L. Ferraioli, R. Guider, S. M. Hossain, D. Navarro-Urrios, A. Pitanti, S. Prezioso, R. Spano, M. Wang, L. Pavesi, Univ. of Trento, Italy.....	175
O1.1	<i>TERAHERTZ EFFECTIVE MAGNETIC ACTIVITY IN MICROSTRUCTURED TiO₂: A NUMERICAL STUDY</i> , C. Kusko, M. Kusko, IMT-Bucharest, Romania.....	181

Session O2: MICROPHOTONICS 2

Poster presentations

O2.1	<i>REPLICATION TECHNIQUES FOR MICRO-OPTICS</i> , P. Obreja, D. Cristea, A. Dinescu, E. Manea, IMT-Bucharest, Romania.....	187
O2.2	<i>FRONT SURFACE TEXTURING PROCESSES FOR SILICON SOLAR CELLS</i> , E. Manea, E. Budianu, M. Purica, C. Podaru, A. Popescu, C. Parvulescu, A. Dinescu, A. Coraci, I. Cernica, F. Babarada*, IMT-Bucharest, *"Politehnica" Univ. of Bucharest, Romania.....	191

Student Paper

O2.3	<i>OPTIMIZATION STUDIES OF SINGLE-TRANSVERSE-MODE 980-nm RIDGE-WAVEGUIDE LASERS</i> , A. Laakso, M. Dumitrescu, M. Suominen, P. Pietila, P. Leinonen, P. Tuomisto, C. Reith, M. Pessa, Tampere Univ. of Technology, Finland.....	195
O2.4	<i>COMPARATIVE CHARACTERIZATION OF PbS MACRO- AND NANO-CRYSTALLINE PHOTORESISTIVE DETECTORS</i> , G. Iordache, M. Buda, V. Stancu, T. Botila, INCD-FM, Bucharest, Romania.....	199
O2.5	<i>SIMULATION EXPERIMENT ON 4H-SiC MILLIMETER-WAVE PHOTO-ILLUMINATED HIGH POWER IMPATT OSCILLATOR</i> , M. Mukherjee, N. Mazumder, K. Goswami*, Visva Bharati Univ., *Jadavpur Univ., Kolkata, India.....	203
O2.6	<i>DESIGN OF A THERMOOPTICAL MODULATOR BASED ON SOI WAVEGUIDES</i> , M. Kusko, F. Comanescu, C. Tibeica, D. Cristea, IMT-Bucharest, Romania.....	207
O2.7 #	<i>PROPOSED TECHNOLOGICAL FLOW OF AN Y-SPLITTER WAVEGUIDE GRATING SENSOR</i> , R. Rebigan, M. Kusko, A. Avram, D. Cristea, IMT-Bucharest, Romania.....	211
O2.8	<i>SiO₂-TiO₂ UNDOPED OR (ER³⁺) DOPED THIN LAYERS FOR INTEGRATE OPTICS PREPARED BY SOL-GEL METHOD</i> , M. Zaharescu, D. Cristea*, P. Obreja*, L. Predoana, M. Gartner, M. Anastasescu, Inst. of Physical Chemistry "Ilie Murgulescu", Bucharest, IMT-Bucharest, Romania.....	215
O2.9	<i>NEGATIVE PHOTOCONDUCTIVITY OF AMORPHOUS Sb₂Se₃ AND Sb₂Se₃:Sn FILMS</i> , M.S. Iovu, I.A. Vasiliev, E.P. Colomeico, Inst. of Applied Physics, Chisinau, Moldova.....	219
O2.10	<i>STRUCTURAL AND ELECTRO-OPTICAL PROPERTIES OF ZnO THIN FILMS</i> , F. Iacomi, C. Baban, R. Apetrei, D. Luca, „Al.I. Cuza” Univ., Iasi, Romania.....	223
O2.11	<i>THE EDFA MODEL BASED ON BDI PROCESSES</i> , F. Vasile, P. Schiopu*, Alcatel-Lucent Romania, Bucharest, *, „Politehnica” Univ. of Bucharest, Romania.....	227

Session M1: ADVANCED MICROWAVE DEVICES & CIRCUITS

Oral presentations

M1.1	<i>COMPACT LOAD-COUPPLING NETWORK FOR MICROWAVE CURRENT MODE CLASS-D POWER AMPLIFIERS</i> , P. Aflaki, R. Negra, F.M. Ghannouchi, Univ. of Calgary, AB, Canada.....	233
M1.2	<i>STUDY OF RECONFIGURABLE MOSTLY DIGITAL RADIO FOR MANET</i> , A. Lecointre, D. Dragomirescu, R. Plana, LAAS-CNRS, Univ. of Toulouse, France.....	237
M1.3	<i>SILICON SUPPORTED MICROWAVE DIRECTIONAL COUPLER METAMATERIAL APPROACH</i> , G. Sajin ¹ , S. Simion ¹ , R. Marcelli ² , F. Craciunoiu ¹ , G. Bartolucci ³ , ¹ IMT-Bucharest, Romania, ² CNR, Inst. for Microelectronics and Microsystems, ³ Univ. of Roma “Tor Vergata”, Roma, Italy.....	241
M1.4	<i>160 GHz ON-CHIP DIPOLE ANTENNA STRUCTURE IN SILICON TECHNOLOGY</i> , D. Neculoiu ^{1,2} , A. Muller ¹ , K. Tang ³ , E. Laskin ³ , S.P. Voinigescu ³ , ¹ IMT-Bucharest, ² Politehnica” Univ. of Bucharest, Romania, ³ Univ. of Toronto, Canada.....	245
M1.5	<i>THE FABRICATION PROCESS OF RF INDUCTOR STRUCTURES IN THE LTCC TECHNOLOGY</i> , G. Radosavljevic, A. Maric, G. Stojanovic, Lj. Zivanov, W. Smetana*, M. Unger*, H. Homolka*, Univ. of Novi Sad, Serbia, *Tchnical Univ. Viena, Austria.....	249

Student Paper

Session M2: RF MEMS**Oral presentations**

M2.1	<i>WIDE BAND GAP SEMICONDUCTOR SAW TYPE DEVICES FOR GHz APPLICATIONS, MANUFACTURED USING NANO-LITHOGRAPHIC TECHNIQUES, A. Muller¹, A. Dinescu¹, G. Konstantinidis², D. Vasilache¹, M. Dragoman¹, C. Morosanu³, G. Sajin¹, D. Neculoiu¹, ¹IMT-Bucharest, Romania, ²FORTH IESL Heraklion, Crete, Greece, ³National Inst. of Material Physics (NIMP), Bucharest, Romania.....</i>	255
M2.2	<i>RF MEMS SWITCHES SUPPORTED BY POLYMERIC STRUCTURES, A. Lucibello, E. Proietti, S. Catoni, L. Frenguelli, R. Marcelli, *G. Bartolucci, CNR-IMM, Roma, *Univ. of Roma "Tor Vergata", Italy.....</i>	259
M2.3	<i>TECNOLOGICAL AND DESIGN IMPROVEMENTS FOR RF MEMS SHUNT SWITCHES, F. Giacomozzi¹, C. Calaza¹, S. Colpo¹, V. Mulloni¹, A. Collini¹, B. Margesin¹, P. Farinelli², F. Casini², R. Marcelli³, G. Mannocchi⁴, L. Vietzorreck⁵, ¹MEMS Group, FBK-irst, Trento, ²Univ. of Perugia, ³CNR-IMM Roma, ⁴Thales Alenia Space, Roma, Italy, ⁵Technical Univ. Munchen, Germany.....</i>	263
M2.4	<i>WHICH ARCHITECTURE TO CHOOSE FOR ROBUST RF-MEMS PHASE SHIFTERS?, V. Puyal, D. Dubuc, K. Grenier, C. Bordas, O. Vendier*, J.-L. Cazaux*, LAAS-CNRS, *Alcatel Alenia Space, Toulouse, France.....</i>	267
M2.5	<i>LOW DESIGN OF MICROMACHINED COPLANAR GROUNDED WAVE-GUIDES, G. De Angelis, A. Lucibello, E. Proietti, S. Catoni, R. Marcelli, CNR-IMM Roma, Italy.....</i>	271
M2.6	<i>DIELECTRIC RESONATORS FOR MICROWAVE AND MILLIMETER WAVE APPLICATIONS, L. Nedelcu, M.I. Toacsan, M.G. Banciu, A. Ioachim, INCD-FM, Bucharest, Romania.....</i>	275

Session M3: RF MEMS, MICROWAVE DEVICES & CIRCUITS**Poster presentations**

M3.1	<i>EFFICIENT HYBRID MODE ANALYSIS OF SHIELDING EFFECT IN ASYMMETRIC COPLANAR STRUCTURE FOR MICROWAVE APPLICATIONS, A. Khodja¹, H. Baudrand², R. Touhami¹, M.C.E. Yagoub³, ¹USTHB Univ., Algiers, Algeria, ²ENSEEIH, Toulouse, France, ³Univ. of Ottawa, Ontario, Canada.....</i>	281
M3.2	<i>HYBRID-MODE ANALYSIS OF THREE-LEVEL MICROWAVE COUPLERS, C. Boularak, M.L. Tounsi, R. Touhami, M.C.E. Yagoub*, USTHB Univ., Algiers, Algeria, *Univ. of Ottawa, Ontario, Canada.....</i>	285
M3.3	<i>ANTENNAS WITH PREFRACTAL GEOMETRY FOR WIRELESS COMMUNICATIONS, G. Goga, A. Hongu, I. Nicolaescu, M.G. Banciu*, A. Ioachim*, Military Technical Academy, *INCD-FM, Bucharest, Romania.....</i>	289
M3.4	<i>MEMBRANE SUPPORTED ALN FBAR STRUCTURES OBTAINED BY MICROMACHINING OF HIGH RESISTIVITY SILICON, D. Neculoiu^{1,4}, D. Vasilache¹, G. Konstantinidis², C. Morosanu³, A. Stavrinidis², A. Kostopoulos², A. Cismaru¹, C. Buiculescu¹, I. Petrini¹, A. Muller¹, ¹IMT-Bucharest, Romania, ²FORTH-IESL-MRG Heraklion, Crete, Greece, ³National Inst. of Material Physics, Bucharest, ⁴"Politehnica" Univ. of Bucharest, Romania.....</i>	293
M3.5	<i>AN INNOVATIVE AND VERSATILE TOPOLOGY FOR TUNABLE BANDPASS FILTER, A. Takacs^{1,3}, D. Neculoiu¹, D. Vasilache¹, A. Muller¹, P. Pons², H. Aubert², R. Plana³, ¹IMT-Bucharest, Romania, ²LAAS-CNRS, Toulouse, France, ³ATM Bucharest, Romania.....</i>	297

Session AM: ADVANCED MATERIALS

Oral presentations

AM.1	<i>OPTICAL AND MICROSTRUCTURAL PROPERTIES OF SOL-GEL TiO_xN_y THIN FILMS</i> , Chr. Trapalis, T. Giannakopoulou, N. Todorova, C. Anastasescu*, M. Anastasescu*, M. Gartner*, NCSR "Demokritos", Athens, Greece, *"Ilie Murgulescu" Inst. of Physical Chemistry, Bucharest, Romania.....	303
AM.2	<i>PREPARATION AND MAGNETIC PROPERTIES OF Fe-W AND Ni-W COMPOSITE COATINGS</i> , H. Chiriac ¹ , A.E. Moga ¹ , C. Gherasim ^{1,2} , N. Lupu ¹ , *National Inst. of Research & Development for Technical Physics, **"Al. I. Cuza" Univ., Iasi, Romania.....	307
AM.3	<i>SINTERING DISTORSION PRODUCED BY DIFFERENCES IN GREEN DENSITY AND SAMPLE SHAPE OF PZT COMPACTED POWDERS</i> , C. Miclea, C. Tanasoiu, I. Spanulescu*, C.F. Miclea, A. Gheorghiu*, L. Amarande, M. Cioangher, L. Trupina, C.T. Miclea*, C. David*, INCD-FM, *Hyperion Univ., Bucharest, Romania.....	311
AM.4	<i>COPRECIPIATION SYNTHESIS OF Ag-DOPED ZnO NANOPOWDERS</i> , A.O. Cadar, C. Roman, L. Gagea, B.A. Matei*, I. Cernica*, Research Inst. for Analytical Instrumentation (ICIA), Cluj-Napoca, *IMT-Bucharest, Romania.....	315
AM.5	<i>SOME CONTRIBUTIONS TO THE UNDERSTANDING OF THE PUZZLE OF PHYSICAL PROCESSES OF DEGRADATION IN IRRADIATED SILICON</i> , S. Lazanu, I. Lazanu*, M.L. Ciurea, *INCD-FM, *Univ. of Bucharest, Romania.....	319
AM.6	<i>SYNTHESIS AND CHARACTERIZATION OF SOME FUNCTIONAL POLYIMIDES</i> , C. Hulubei, E. Hamciuc, M. Bruma, A. Muller*, "Petru Poni" Inst. of Macromolecular Chemistry, Iasi, *IMT- Bucharest, Romania.....	323
AM.7	<i>ZnO MICRO/NANO STRUCTURES BY MOCVD AND VAPOUR TRANSPORT TECHNIQUE : GROWTH AND CHARACTERIZATION</i> , E. Rusu ¹ , A. Burlacu ¹ , V. Ursaki ¹ , G. Stratan ¹ , M. Purica ² , E. Budianu ² , E. Monaico ³ , ¹ Inst. of Applied Physics, Chisinau, Moldova, ² IMT-Bucharest, Romania, ³ Technical Univ. of Moldova, Chisinau, Moldova.....	327

Session M&N: MATERIALS FOR MICRO AND NANO SCALE

Poster presentations

M&N.1	<i>GAS-SENSING BY POLYMER-IRON NANOCOMPOSITE MATERIALS</i> , A. Tomescu, C.E. Simion, R. Alexandrescu*, I. Morjan*, M. Scarisoreanu*, National Inst. of Materials Physics, *INFLPR, Bucharest, Romania.....	333
M&N.2	<i>THE INFLUENCE OF THE WETTING LAYER MORPHOLOGY ON THE NUCLEATION AND THE EVOLUTION OF InAs/GaAs (001) QUANTUM DOTS</i> , O. Bute, Gh.V. Cimpoca, E. Placidi*, F. Arciprete*, F. Patella*, M. Fanfoni*, A. Balzarotti*, "Valahia" Univ. of Targoviste, Romania, *Univ. of Roma "Tor Vergata", Roma, Italy.....	337
M&N.3	<i>INVESTIGATION OF ZnO NANOSTRUCTURES PREPARED BY CHEMICAL DEPOSITION AND RAPID PHOTO-THERMAL PROCESSING TECHNOLOGY</i> , O. Lupan ^{1,2} , S. Shishiyanu ¹ , L. Chow ² , T. Shishiyanu ¹ , V. Sontea ¹ , E. Monaico ³ , A. Schulte ² , S. Park ² , ¹ Department of Microelectronics and Semiconductor Devices, Technical Univ. of Moldova, ² Univ. of Central Florida, Orlando, FL, USA, ³ National Center for Materials Study and Testing, Technical Univ. of Moldova, Chisinau, Moldova.....	341
M&N.4	<i>NANOSTRUCTURED SILICON FOR OPTICAL BIOSENSORS</i> , M. Miu, I. Kleps, L. Pavesi*, F. Craciunoiu, T. Ignat, A. Dinescu, M. Simion, IMT-Bucharest, Bucharest, Romania, *Univ. of Trento, Povo, Italy.....	345

M&N.5	<i>EFFECT OF Sn DOPANT ON THE PROPERTIES OF ZnO NANOROD ARRAYS, O. Lupan^{1,2}, L. Chow², V. Ursaki³, E. Monaico⁴, I. Tiginyanu³, S. Shishiyanu¹, T. Shishiyanu¹, S. Park², A. Schulte², ¹Department of Microelectronics and Semiconductor Devices, Technical Univ. of Moldova, ²Univ. of Central Florida, Orlando, FL, USA. ³Inst. of Applied Physics, ⁴National Center for Materials Study and Testing, Technical Univ. of Moldova, Chisinau, Moldova.....</i>	349
M&N.6	<i>AN XPS STUDY ON N DOPED TiO₂ SOL-GEL THIN FILMS, P. Osiceanu, M. Anastasescu, C. Anastasescu, C. Trapalis*, T. Giannakopoulou*, N. Todorova*, "Ilie Murgulescu" Inst. of Physical Chemistry, Bucharest, Romania, *NCSR "Demokritos", Athens, Greece.....</i>	353
M&N.7	<i>AROMATIC POLYIMIDES CONTAINING CYANO SUBSTITUENTS FOR HIGH PERFORMANCE APPLICATIONS, E. Hamciuc, I. Bacosca, M. Bruma, M. Ignat*, "Petru Poni" Inst. of Macromolecular Chemistry, Iasi, *INCIE ICPE-CA, Bucharest, Romania.....</i>	357
M&N.8	<i>FLUORINATED HETEROCYCLIC POLYIMIDES FOR POTENTIAL USE IN RF MEMS DEVICES, M. Bruma, I. Sava, E. Hamciuc, C. Hamciuc, C. Buiculescu*, "Petru Poni" Inst. of Macromolecular Chemistry, Iasi, *IMT-Bucharest, Romania.....</i>	361
M&N.9	<i>HYDROXY - FUNCTIONALIZED POLYIMIDES AS MATERIALS FOR ADVANCED APPLICATIONS, E. Hamciuc¹, M. Bruma¹, B. Schulz², M. Szesztay³, G. Telipan⁴, ¹"Petru Poni" Inst. of Macromolecular Chemistry, Iasi, Romania, ²Inst. for Thin Film Technology and Microsensorics, Teltow, Germany, ³Chemical Research Center, Budapest, Hungary, ⁴INCIE ICPE-CA, Bucharest, Romania.....</i>	365
M&N.10	<i>PHOTOCHROMIC BEHAVIOR OF NEW AZO-POLYIMIDES, I. Sava, A.-M. Rezmerita*, N. Hurdac*, "Petru Poni" Inst. of Macromolecular Chemistry, *Technical Univ. "Gh. Asachi", Iasi, Romania.....</i>	369
M&N.11	<i>THE DEVELOPMENT OF CRYSTALLINE Sb₂S₃ THIN FILMS AS BUFFER LAYER OR AS ABSORBER MATERIAL FOR THREE-DIMENSIONAL (3D) SOLAR CELLS, S.A. Manolache, A. Duta, Transilvania Univ. of Brasov, Romania.....</i>	373
M&N.12	<i>X-RAY LUMINESCENCE IN ZnIn₂S₄, CdGa₂S₄ AND Zn₃In₂S₆, A. Machuga¹, R. Radu¹, V. Pintea¹, E. Arama², V. Zhitar³, T. Shemyakova³, ¹Technical Univ. of Moldova, ²"N. Testemitsanu" Medical Univ. of Moldova, ³Inst. of Applied Physics, Chisinau, Moldova.....</i>	377
M&N.13	<i>NANO-METROLOGY BETWEEN NECESSITY AND REALITY, D. Apostol, P.C. Logofatu, R. Muller*, INFPLR, Bucharest, *IMT-Bucharest, Romania.....</i>	381

Session D: ADVANCED DEVICES AND STRUCTURES

Oral presentations

INVITED PAPER	<i>VERTICAL MOSFETs FOR HIGH PERFORMANCE, LOW COST CMOS, S. Hall, L. Tan, O. Buiu, M.M. Hakim*, T. Uchino*, P. Ashburn*, W. Redman-White*, Univ. of Liverpool, *Univ. of Southampton, UK.....</i>	387
INVITED PAPER	<i>SMALL SLOPE MICRO/NANO-ELECTRONIC SWITCHES, A. M. Ionescu, K. Boucart, K.E. Moselund, V. Pott, D. Tsamados, Ecole Polytechnique Fédérale de Lausanne, Switzerland.....</i>	397
D.1	<i>ONE DIMENSIONAL MODEL FOR THE DURATION OF THE HIGH BREAKDOWN PHASE IN DEEP DEPLETION POWER DEVICES, E. Napoli, Univ. of Napoli Federico II, Italy.....</i>	403
D.2	<i>A SINGLE POLY CMOS PROCESS EVALUATION FOR FLOATING GATE APPLICATIONS, M. Badila, T. Dunca, P. Cosmin, Catalyst Semiconductor Inc., CA, USA.....</i>	407
D.3	<i>FABRICATION OF DIAMOND BASED SCHOTTKY BARRIER DIODES WITH OXIDE RAMP TERMINATION, G. Brezeanu¹, M. Avram², M. Brezeanu³, C. Boianeanu¹, F. Udrea³, G.A.J. Amaratunga³, ¹"Politehnica" Univ. of Bucharest, ²IMT-Bucharest, Romania, ³Univ. of Cambridge, UK.....</i>	411

D.4	<i>Si DIODE TEMPERATURE SENSOR BEYOND 300°C</i> , S. Santra, P.K. Guha, M.S. Haque, S.Z. Ali, F. Udrea, Univ. of Cambridge, UK.....	415
D.5 #	<i>ENSEMBLE MONTE CARLO SIMULATION OF A PSEUDOMORPHIC HEMT STRUCTURE</i> , C. Amza, I. Cimpian*, M.D. Profirescu*, ATC ROM S.R.L., Bucharest, *"Politehnica" Univ. of Bucharest, Romania.....	419

Session IC1: LOW POWER, HIGH SPEED ANALOG ICs 1

Oral presentations

IC1.1	<i>ARCHITECTURE CONSIDERATIONS FOR 60 GHz PULSE TRANSDUCER FRONT-ENDS</i> , M. Kraemer ^{1,2} , A. Lecointre ^{1,2} , D. Dragomirescu ^{1,2} , R. Plana ¹ , ¹ LAAS-CNRS, Univ. of Toulouse, ² INSA Toulouse, France.....	425
IC1.2	<i>TECHNIQUES OF TEMPERATURE COMPENSATION IN A RC OSCILLATOR</i> , M. Sararoiu, J. Fehle*, Infineon Technologies Romania, Bucharest, Romania, *Infineon Technologies, Villach, Austria.....	429
IC1.3	<i>LOW POWER CURRENT MODE POLY-SILICON TFT DIGITAL CIRCUIT DESIGN METHOD FOR HIGH SPEED SOP COMPONENTS</i> , J.-C. Lee, M.-P. Hong*, J.Y. Jeong*, Mixed IC Design Div., SELOCO Inc., Seoul, *Univ. of Suwon, Kyongki, Korea.....	433
IC1.4	<i>1.5A DDR2 TERMINATION REGULATOR</i> , C. Stanescu, G. Aungurencei*, F. Franc*, G. Voicu*, Catalyst Semiconductor Romania SRL, Bucharest, Romania, *Catalyst Semiconductor Inc., Sunnyvale, USA.....	437
IC1.5	<i>AREA EFFICIENT CHARGE PUMP DESIGN WITH CONSTANT OUTPUT POWER OVER THE WHOLE SUPPLY RANGE</i> , D. Dinu, H. Gietler*, Infineon Technologies Romania, Bucharest, Romania, *Infineon Technologies Austria, Villach, Austria.....	441

Session IC2: LOW POWER, HIGH SPEED ANALOG ICs 2

Oral presentations

IC2.1	<i>VOLTAGE FEEDBACK OPERATIONAL AMPLIFIER DC OPEN LOOP GAIN NONLINEARITY MEASUREMENTS SPICE SET-UP</i> , C. Neacsu, V. Chesaru, C. Dan*, M. Bodea*, O2 Micro Romania, Bucharest, *"Politehnica" Univ. of Bucharest, Romania.....	447
IC2.2	<i>HIGH FREQUENCY PROGRAMMABLE WIDE-BAND FREQUENCY DIVIDER DESIGN FOR CMOS SOFTWARE DEFINED RADIO TRANCEIVERS</i> , S. Spiridon, F. Agavrioloaie, M. Serban, AsicAhead International SRL, Bucharest, Romania.....	451
IC2.3	<i>BEHAVIOR MODELLING APPLICATION FOR AUTOMOTIVE INDUSTRY</i> , C. Dolea, A. Mocanu*, Infineon Technologies Romania, Bucharest, *"G. Asachi" Technical Univ., Iasi, Romania.....	455
IC2.4	<i>OPTIMAL HARDWARE IMPLEMENTATION OF A FEEDFORWARD NEURAL NETWORK TOPOLOGY USING A GENETIC ALGORITHM FOR PRUNNING</i> , C.I. Vizitiu, A. Radu, T. Oroian, C. Molder, Military Technical Academy, Bucharest, Romania.....	459
IC2.5	<i>BURST MODE SWITCHING MECHANISM FOR AN INDUCTORLESS DC-DC CONVERTER</i> , M. Budaes, L. Goras, „Gh. Asachi” Technical Univ. Iasi, Romania.....	463
IC2.6	<i>A 10GHz UWB CMOS LNA</i> , C.M. Pavaluta, Infineon Technologies Romania, Bucharest, Romania.....	467

Student Paper

Session D&IC: DEVICES AND ICs
Poster presentations

D&IC.1	<i>LASER TRIMMING MODELING OF THIN FILM INTEGRATED RESISTORS, A. Manolescu, A.M. Manolescu, “Politehnica” Univ. of Bucharest, Romania.....</i>	473
D&IC.2	<i>MODIFIED SOI-MOSFET STRUCTURE WITH SHALLOWS DIFFUSIONS, C. Ravariu, A. Rusu, F. Ravariu*, “Politehnica” Univ. of Bucharest, *IMT-Bucharest, Romania.....</i>	477
D&IC.3	<i>CALCULATION OF THE DEPLETION REGION WIDTH AND BARRIER CAPACITANCE OF DIFFUSED SEMICONDUCTOR JUNCTIONS WITH APPLICATION TO REACH-THROUGH BREAKDOWN VOLTAGE OF SEMICONDUCTOR DEVICES WITH DIFFUSED BASE, M.J. Cristea, “Politehnica” Univ. of Bucharest, Romania.....</i>	481
D&IC.4	<i>THE VOLTAGE DEPENDENCE OF REVERSE CURRENT OF SEMICONDUCTOR PN JUNCTIONS AND ITS DISTRIBUTION OVER THE DEVICE AREA, V.V.N. Obreja, IMT-Bucharest, Romania.....</i>	485
D&IC.5 #	<i>ON THE TUNING POSSIBILITIES OF AN RF BANDPASS FILTER WITH SIMULATED INDUCTOR, C. Andriesei, L. Goras, Faculty of Electronics and Telecommunications, Iasi, Romania.....</i>	489
D&IC.6 #	<i>ELECTRO-THERMAL SIMULATION ENVIRONMENT FOR DIGITAL ICs, V. Moleavin, M.D. Profirescu*, Microchip Development Romania, Bucharest, **“Politehnica” Univ. of Bucharest, Romania.....</i>	493
D&IC.7 #	<i>A PROCEDURE BASED ON THE ANOVA METHOD FOR ESTIMATING THE MAXIMUM NUMBER OF GENERATIONS FOR OPTIMIZATION GENETIC ALGORITHMS, I. Codreanu, IMT-Bucharest, Romania.....</i>	497
D&IC.8	<i>STACKS OR FILE-REGISTERS IN CELLULAR COMPUTING ?, M. Stoian, G. Stefan, “Politehnica” Univ. of Bucharest, Romania.....</i>	501
D&IC.9	<i>DESIGN ASPECTS FOR GATE DRIVER OF POWER SWITCH, C. Ionascu, Infineon Technologies Romania SCS, Bucharest, Romania.....</i>	505
D&IC.10	<i>VLSI IMPLEMENTATION OF HIGH-SPEED CELLULAR AUTOMATA ENCRYPTION ALGORITHM, P. Angheliescu, E. Sofron, S. Ionita, Univ. of Pitesti, Romania.....</i>	509
D&IC.11	<i>PROTECTION FUNCTIONS IN INTEGRATED LOW SIDE SWITCHES, A. Danchiv, Infineon Technologies Romania, Bucharest, Romania.....</i>	513
D&IC.12	<i>CMOS DIFFERENTIAL STRUCTURE WITH IMPROVED LINEARITY AND INCREASED FREQUENCY RESPONSE, C. Popa, A.M. Manolescu, “Politehnica” Univ. of Bucharest, Romania.....</i>	517
D&IC.13	<i>TWO BEAMS MODIFIED LEMNISCATE UNDULATOR, S. Miclos¹, M.I. Rusu¹, D. Tenciu¹, V. Savu¹, L. Giurgiu², F. Scarlat³, V.I.R. Niculescu³, ¹National Inst. of R&D for Optoelectronics INOE-2000, ²Univ. of Bucharest, ³INFPLR, Bucharest, Romania.....</i>	521
D&IC.14	<i>SOFTWARE SIMULATION AND PERFORMANCE ANALYSIS FOR TURBO ENCODING/DECODING CHIP COMPONENTS FOR MAGNETIC RECORDING CHANNELS, P.M. Putinica, St. Stancescu, “Politehnica” Univ. of Bucharest, Romania.....</i>	525
D&IC.15	<i>APPLICATION OF A NEW BODY CONTACT TO SOI LDMOSFET DEVICES, THREE-DIMENSIONAL SIMULATION, A. Daghighi, M.A. Osman*, Islamic Azad Univ. Isfahan, Iran, *Washington State Univ., Pullman, WA, USA.....</i>	529
D&IC.16	<i>A SELF-CONSISTENT MODELING OF 4H-SiC SCHOTTKY BARRIER DIODES, M.B. Tayel, A.M. El-Shawarby, Alexandria Univ., Egypt.....</i>	533
D&IC.17	<i>LOW-POWER CARRY LOOK-AHEAD ADDER WITH MULTI-THRESHOLD VOLTAGE CMOS TECHNOLOGY, J.B. Kim, D.W. Kim*, Kangwon National Univ., *Samsung SDI Co., Ltd, Korea.....</i>	537

Student Paper

Session S: STUDENTS PAPER

Oral presentations

S.1	<i>MHz OSCILLATOR BASED ON VIBRATING GATE MOS TRANSISTOR</i> , Al. Rusu, M. Mazza* , Y.S. Chauhan* , A.M. Ionescu* , “Politehnica” Univ. of Bucharest, Romania, *Ecole Polytechnique Federale de Lausanne, Switzerland.....	543
S.2	<i>AN AVERAGING SMALL-SIGNAL MODEL FOR A DC-DC SWITCHED CONVERTER</i> , M. Budaes, L. Goras , „Gh. Asachi” Technical Univ., Iasi, Romania.....	547
S.3	<i>EXPERIMENTAL VALIDATION OF A SIMPLE ANALYTICAL MODEL FOR THE ELECTRICAL BEHAVIOUR OF NANOSCALE MOSFETS</i> , A. Sevcenco, G. Brezeanu, M. Badila* , F. Draghici, I. Rusu, A. Visoreanu , “Politehnica” Univ. of Bucharest, Romania, *Catalyst Semiconductor, Santa Clara, CA, USA.....	551
S.4	<i>NON INVERTING DIFFERENTIAL ASYMMETRICAL CMOS COMPARATOR WITH INTRINSIC HYSTERESIS AND ADJUSTABLE ASYMMETRY</i> , R. Ionescu, O. Mita, F. Vladoianu* , G. Brezeanu , “Politehnica” Univ. of Bucharest, *Atmel Romania S.R.L., Bucharest, Romania.....	555
S.5	<i>DESIGN AND FABRICATION OF NEW MICROFLUIDIC VALVES</i> , M.A. Avram, M. Avram , IMT-Bucharest, Romania.....	559
S.6	<i>NOISE IN CMOS LDOS</i> , O. Profirescu², C. Dinca¹, C. Stanescu¹ , ¹ Catalyst Semiconductor Romania S.R.L., Bucharest, ² Politehnica” Univ. of Bucharest, Romania.....	563
S.7	<i>ANALYSIS OF DISPLACEMENTS OF A POLYMERIC MICROGRIPPER</i> , R. Voicu, C. Tibeica, L. Eftime, R. Muller , IMT-Bucharest, Romania.....	567
S.8	<i>AN ANALYSIS ON DIGITAL MODULATION TECHNIQUES FOR SOFTWARE DEFINED RADIO APPLICATIONS</i> , A. Tarniceriu, B. Iordache, S. Spiridon* , “Politehnica” Univ. of Bucharest, *AsicAhead International SRL, Bucharest, Romania.....	571
S.9	<i>PERCOLATION PHENOMENA IN SILICON – BASED NANOCRYSTALLINE SYSTEMS</i> , A.M. Lepadatu, E. Rusnac, I. Stavarache , INCD-FM, Bucharest, Romania.....	575